

**Amendments to the Specification**

Please replace the paragraph beginning at page 6, line 7 with the following paragraph:

Fig. 1 is a diagram useful for understanding the operation of a resonant microcavity anode (RMA) type FED device 100 which can be used with the present invention. The FED device 100 is comprised of a cathode 101 formed from an emitter array 102 that is positioned on a silicon substrate 114. An RMA type anode or array ~~or of~~ anodes 104 is spaced apart from the cathode and positioned behind glass 108. The anode is preferably comprised of a thin film phosphor 106 which can be formed between dielectric mirrors 110. As electrons 118 excite the thin film phosphor 106, they cause the emission of light through glass 108 in the direction of arrow 116. A control grid may also be provided for modulating the intensity of electrons 118 directed toward anode 104.